SLOS072 - D2142, MARCH 1978-REVISED SEPTEMBER 1990

- Continuous-Short-Circuit Protection
- Wide Common-Mode and Differential Voltage Ranges
- No Frequency Compensation Required
- Low Power Consumption
- No Latch-Up
- Unity Gain Bandwidth 3 MHz Typical
- Gain and Phase Match Between Amplifiers
- Designed to Be Interchangeable With Raytheon RC4136, RM4136, and RV4136
- Low Noise . . . 8 nV√Hz Typ at 1 kHz

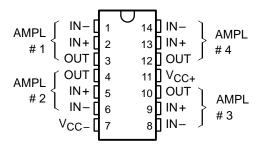
description

The RC4136, RM4136, and RV4136 are quad high-performance operational amplifiers with each amplifier electrically similar to the uA741 except that offset null capability is not provided.

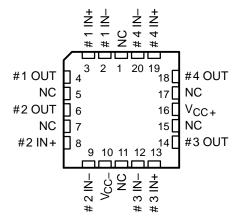
The high common-mode input voltage range and the absence of latch-up make these amplifiers ideal for voltage-follower applications. The devices are short-circuit protected and the internal frequency compensation ensures stability without external components.

The RC4136 is characterized for operation from 0°C to 70°C, the RM4136 is characterized for operation over the full military temperature range of -55°C to 125°C, and the RV4136 is characterized for operation from -40°C to 85°C.

RM 4136 . . . J OR W PACKAGE ALL OTHERS . . . D OR N PACKAGE (TOP VIEW)

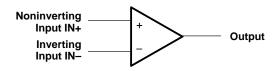


RM4136 FK CHIP CARRIER PACKAGE (T0P VIEW)



NC-No internal connection

symbol (each amplifier)



AVAILABLE OPTIONS

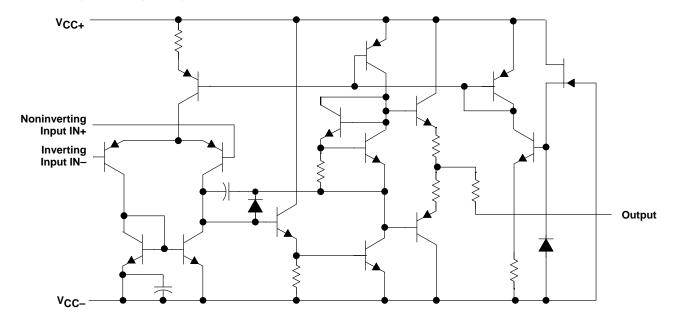
		PACKAGE							
T_A		SMALL-OUTLINE	CHIP CARRIER	CERAMIC DIP	PLASTIC DIP	FLAT			
	V _{IO} MAX	(D)	(FK)	(J)	(N)	(W)			
0°C to	at 25°C								
70°C									
-40 °C to	6 mV	RC4136D	_	_	RC4136N	_			
85°C									
−55°C to	6 mV	RV4136D	_	_	RV4136N				
125°C									

The D packages are available taped and reeled. Add the suffix R to the device type, (e.g., RC4136DR).

RM4136W



schematic (each amplifier)



absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

		RC4136	RM4136	RV4136	UNIT						
Supply voltage V _{CC+} (see Note 1)		18	22	18	V						
Supply voltage V _{CC} (see Note 1)	oltage V _{CC} (see Note 1)		oltage V _{CC} (see Note 1)		oltage V _{CC} (see Note 1)		oltage V _{CC} (see Note 1)		-22	-18	V
Differential input voltage (see Note 2)	ial input voltage (see Note 2)			±30	V						
Input voltage (any input, see Notes 1 and 3)		±15	±15	±15	V						
Duration of output short-circuit to ground, one (see Note 4)	amplifier at a time	unlimited	unlimited	unlimited							
Continuous total dissipation		See Dissipation Rating Table									
Operating free-air temperature range		0 to 70	-55 to 125	-40 to 85	°C						
Storage temperature range		-65 to 150	-65 to 150	-65 to 150	°C						
Case temperature for 60 seconds	FK package	_	260	_	°C						
ad temperature 1,6 mm (1/16 inch) om case for 60 seconds J or W package		_	300	_	°C						
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds D or N package		260	_	260	°C						

- NOTES: 1. All voltage values, unless otherwise noted, are with respect to the midpoint between V_{CC+} and V_{CC-}.
 - 2. Differential voltages are at the noninverting input terminal with respect to the inverting input terminal.
 - 3. The magnitude of the input voltage must never exceed the magnitude of the supply voltage or 15 V, whichever is less.
 - 4. Temperature and/or supply voltages must be limited to ensure that the dissipation rating is not exceeded.

DISSIPATION RATING TABLE

PACKAGE	T _A ≤ 25°C POWER RATING	DERATING FACTOR	DERATE ABOVE T _A	T _A = 70°C POWER RATING	T _A = 85°C POWER RATING	T _A = 125°C POWER RATING
D	800 mW	7.6 mW/°C	45°C	608 mW	494 mW	_
FK	800 mW	11.0 mW/°C	77°C	800 mW	715 mW	275 mW
J	800 mW	11.0 mW/°C	77°C	800 mW	715 mW	275 mW
N	800 mW	9.2 mW/°C	63°C	736 mW	598 mW	_
W	800 mW	8.0 mW/°C	50°C	640 mW	520 mW	200 mW



recommended operating conditions

	MIN	NOM MAX	UNIT
Supply voltage, V _{CC+}	5	15	V
Supply voltage, V _{CC} _	-5	-15	V

electrical characteristics at specified free-air temperature, $V_{CC+} = 15 \text{ V}$, $V_{CC-} = -15 \text{ V}$

				F	RC4136	;	RM4136			RV4136			
F	PARAMETER	TEST CONDITIONS†		MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	UNIT
			25°C		0.5	6		0.5	4		0.5	6	
Vю	Input offset voltage	VO = 0	Full range			7.5			6			7.5	mV
			25°C		5	200		5	1.50		5	200	
liO	Input offset current	VO = 0	Full range			300			500			500	nA
			25°C		140	500		140	400		140	500	
IB	Input bias current	AO = 0	Full range			800			1500			1500	nA
Vi	Input voltage range		25°C	±12	±14		±12	±14		±12	±14		V
	Maximum peak	$R_L = 10 \text{ k}\Omega$	25°C	±12	±14		±12	±14		±12	±14		
Vом	output voltage	$R_L = 2 k\Omega$	25°C	±10	±13		±10	±13		±10	±13		V
	swing	$R_L \ge 2 k\Omega$	Full range	±10			±10			±10			
AVD	Large-signal differential voltage	$V_0 = \pm 10 \text{ V},$	25°C	20	300		50	350		20	300		V/mV
7.00	amplification	$R_L \ge 2 k\Omega$	Full range	15			25			15			*////
B ₁	Unity-gain bandwith		25°C		3			3.5			3		MHz
rį	Input resistance		25°C	0.3*	5		0.3*	5		0.3*	5		MΩ
CMRR	Common-mode rejection ratio	$V_O = 0$, $R_S = 50 \Omega$	25°C	70	90		70	90		70	90		dB
	Supply voltage	$V_{CC} = \pm 9 \text{ V to}$											
ksvs	sensitivity	±15 V,	25°C		30	150		30	150		30	150	μV/V
	$(\Delta V_{IO}/\Delta V_{CC})$	V _O = 0											
V _n	Equivalent in- put noise voltage (closed-loop)	$A_{VD} = 100,$ BW = 1 Hz, f = 1 kHz, $R_{S} = 100 \Omega$	25°C		8			8			8		nV√Hz
			25°C		5	11.3		5	11.3		5	11.3	
^I CC	Supply current (All four amplifiers)	V _O = 0,	MIN T _A		6	13.7		6	13.3		6	13.7	mA
	(All lour amplifiers)	load	MAX T _A		4.5	10		4.5	10		4.5	10	
	Total power	l.,	25°C		150	340		150	340		150	340	
P_{D}	dissipation	V _O = 0, No	MIN T _A		180	400		180	400		180	400	mW
	(All four amplifiers)	load	MAX T _A		135	300		135	300		135	3 00	
V ₀₁ /V ₀₂	Crosstalk attenuation	$A_{VD} = 100,$ f = 10 kHz, $R_{S} = 1 \text{ k}\Omega$	25°C		105			105			105		dB

^{*} This parameter is not production tested.

[†] All characteristics are measured under open-loop conditions with zero common-mode input voltage unless otherwise specified. Full range is 0°C to 70°C for RC4136, -55°C to 125°C for RM4136, and -40°C to 85°C for RV4136.

RC4136, RM4136, RV4136 QUAD HIGH-PERFORMANCE OPERATIONAL AMPLIFIERS

operating characteristics, V_{CC+} = 15 V, V_{CC-} = -15 V, T_A = 25°C

PARAMETER			RC41	36, RV4	136	RM4136				
		TEST CONDITIONS			TYP	MAX	MIN	TYP	MAX	UNIT
t _r	Rise time	V _I = 20 mV,	$R_L = 2 k\Omega$,		0.13		0.13			
	Overshoot factor	C _L = 100 pF			5%			5%		μs
SR	Slew rate at unity gain	V _I = 10 V,	$R_L = 2 k\Omega$,	1.7		4.7		4.7		V/uo
SK		C _L = 100 pF						1.7		V/µs

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